

# XP152A12C0MR-G

TOREX

ETR1121\_003

Power MOSFET

## ■GENERAL DESCRIPTION

The XP152A12C0MR-G is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

In order to counter static, a gate protect diode is built-in.

The small SOT-23 package makes high density mounting possible.

## ■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

## ■FEATURES

**Low On-State Resistance** :  $R_{ds(on)} = 0.3\Omega$  @  $V_{gs} = -4.5V$   
:  $R_{ds(on)} = 0.5\Omega$  @  $V_{gs} = -2.5V$

**Ultra High-Speed Switching**

**Gate Protect Diode Built-in**

**Driving Voltage** : -2.5V

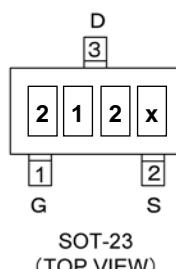
**P-Channel Power MOSFET**

**DMOS Structure**

**Small Package** : SOT-23

**Environmentally Friendly** : EU RoHS Compliant, Pb Free

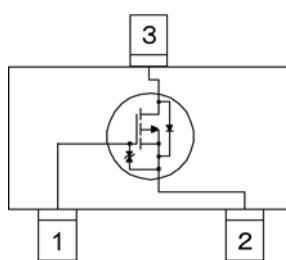
## ■PIN CONFIGURATION/ MARKING



G : Gate  
S : Source  
D : Drain

\* x represents production lot number.

## ■EQUIVALENT CIRCUIT



P-channel MOSFET  
( 1 device built-in )

## ■PIN ASSIGNMENT

PRODUCTS	PACKAGE	ORDER UNIT
XP152A12C0MR	SOT-23	3,000/Reel
XP152A12C0MR-G <sup>(*)</sup>	SOT-23	3,000/Reel

<sup>(\*)</sup> The "-G" suffix denotes Halogen and Antimony free as well as being fully RoHS compliant.

## ■ABSOLUTE MAXIMUM RATINGS

T<sub>a</sub> = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain - Source Voltage	V <sub>dss</sub>	-20	V
Gate - Source Voltage	V <sub>gss</sub>	±12	V
Drain Current (DC)	I <sub>d</sub>	-0.7	A
Drain Current (Pulse)	I <sub>dp</sub>	-2.8	A
Reverse Drain Current	I <sub>dr</sub>	-0.7	A
Channel Power Dissipation *	P <sub>d</sub>	0.5	W
Channel Temperature	T <sub>ch</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55~150	°C

\* When implemented on a ceramic PCB

## ■ ELECTRICAL CHARACTERISTICS

### DC Characteristics

T<sub>a</sub> = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	Idss	V <sub>ds</sub> = -20V, V <sub>gs</sub> = 0V	-	-	-10	μA
Gate-Source Leak Current	I <sub>gss</sub>	V <sub>gs</sub> = ±12V, V <sub>ds</sub> = 0V	-	-	±10	μA
Gate-Source Cut-Off Voltage	V <sub>gs(off)</sub>	I <sub>d</sub> = -1mA, V <sub>ds</sub> = -10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *1	R <sub>ds(on)</sub>	I <sub>d</sub> = -0.4A, V <sub>gs</sub> = -4.5V	-	0.23	0.30	Ω
		I <sub>d</sub> = -0.4A, V <sub>gs</sub> = -2.5V	-	0.37	0.50	Ω
Forward Transfer Admittance *1	Y <sub>fs</sub>	I <sub>d</sub> = -0.4A, V <sub>ds</sub> = -10V	-	1.5	-	S
Body Drain Diode Forward Voltage	V <sub>f</sub>	I <sub>f</sub> = -0.7A, V <sub>gs</sub> = 0V	-	-0.8	-1.1	V

\*1 Effective during pulse test.

### Dynamic Characteristics

T<sub>a</sub> = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	C <sub>iss</sub>	V <sub>ds</sub> = -10V, V <sub>gs</sub> = 0V f= 1MHz	-	180	-	pF
Output Capacitance	C <sub>oss</sub>		-	120	-	pF
Feedback Capacitance	C <sub>rss</sub>		-	60	-	pF

### Switching Characteristics

T<sub>a</sub> = 25°C

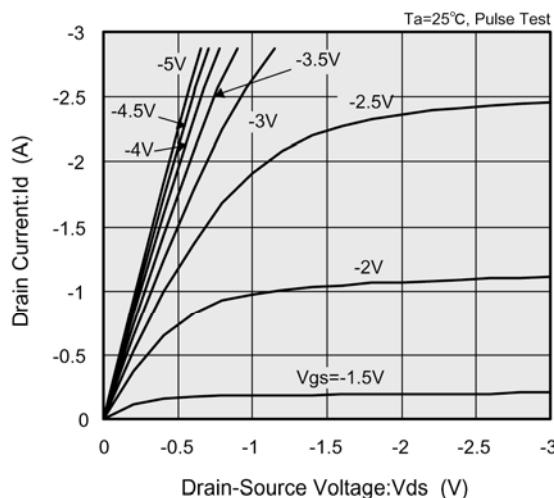
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	t <sub>d</sub> (on)	V <sub>gs</sub> = -5V, I <sub>d</sub> = -0.4A V <sub>dd</sub> = -10V	-	5	-	ns
Rise Time	t <sub>r</sub>		-	20	-	ns
Turn-Off Delay Time	t <sub>d</sub> (off)		-	55	-	ns
Fall Time	t <sub>f</sub>		-	70	-	ns

### Thermal Characteristics

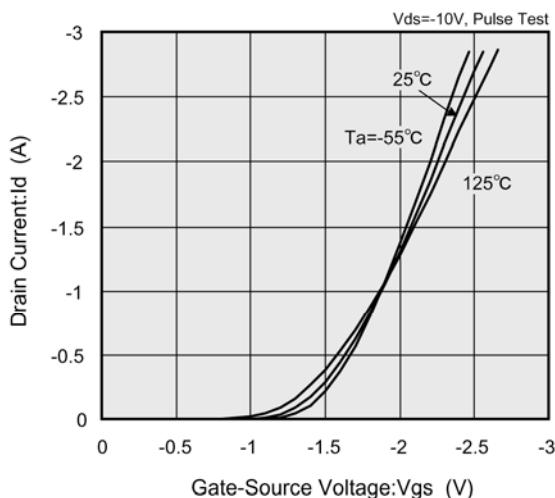
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	R <sub>th</sub> (ch-a)	Implement on a ceramic PCB	-	250	-	°C/W

## ■ TYPICAL PERFORMANCE CHARACTERISTICS

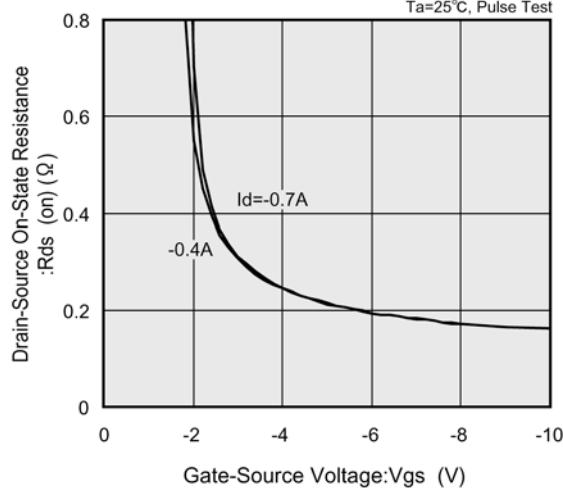
(1) Drain Current vs. Drain-Source Voltage



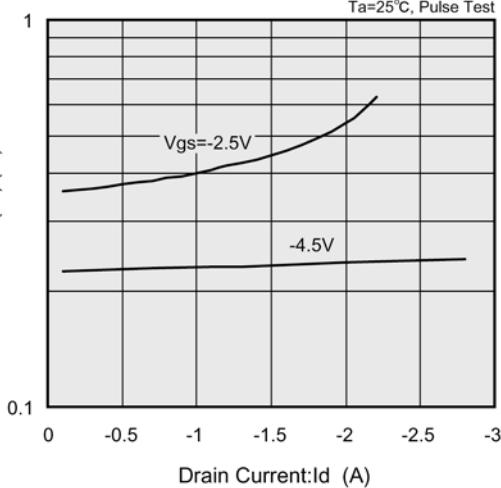
(2) Drain Current vs. Gate-Source Voltage



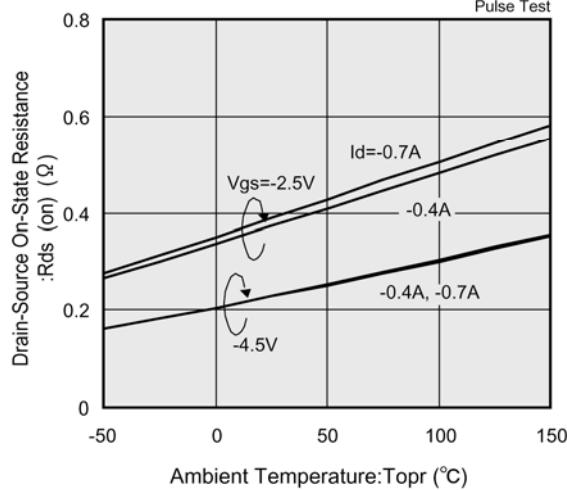
(3) Drain-Source On-State Resistance vs. Gate-Source Voltage



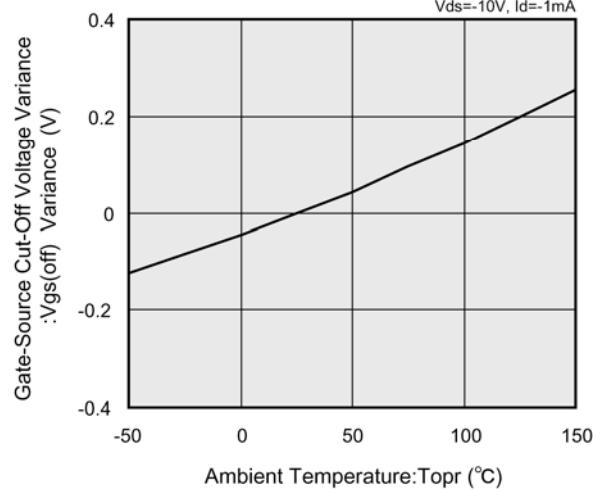
(4) Drain-Source On-State Resistance vs. Drain Current



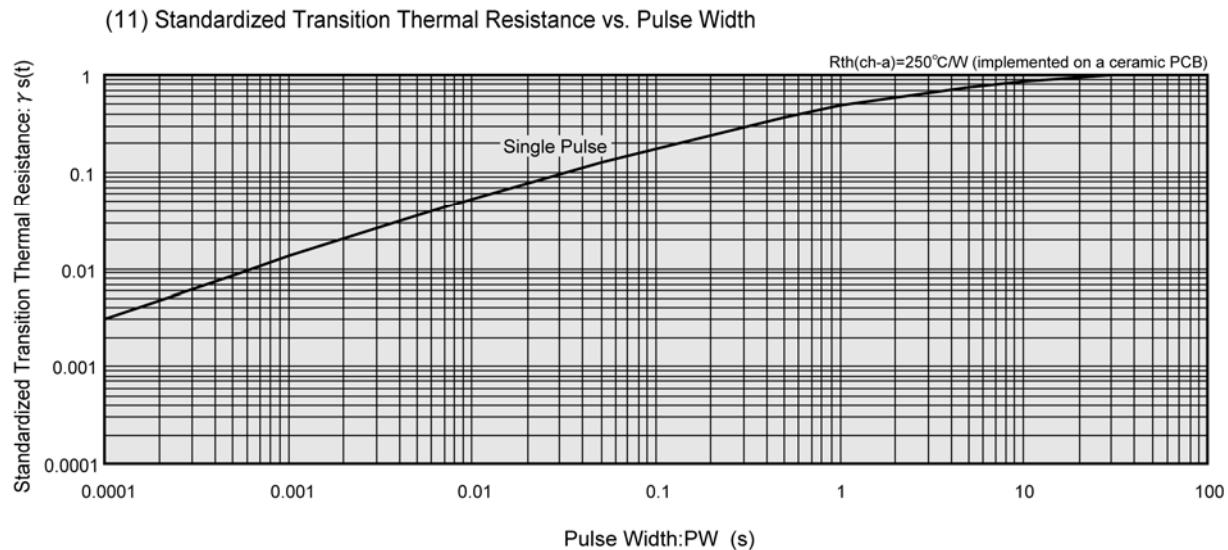
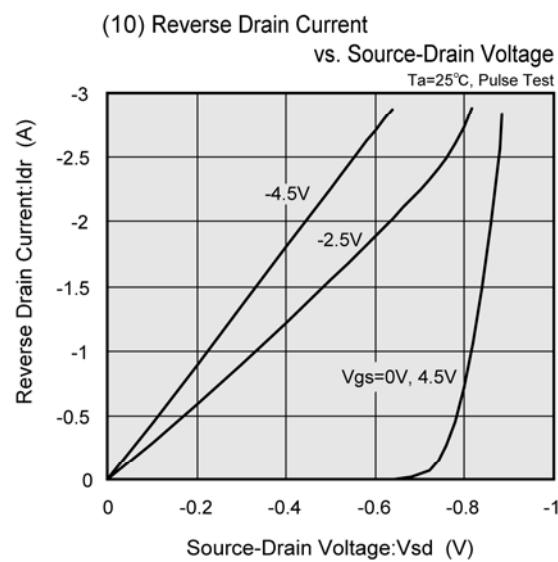
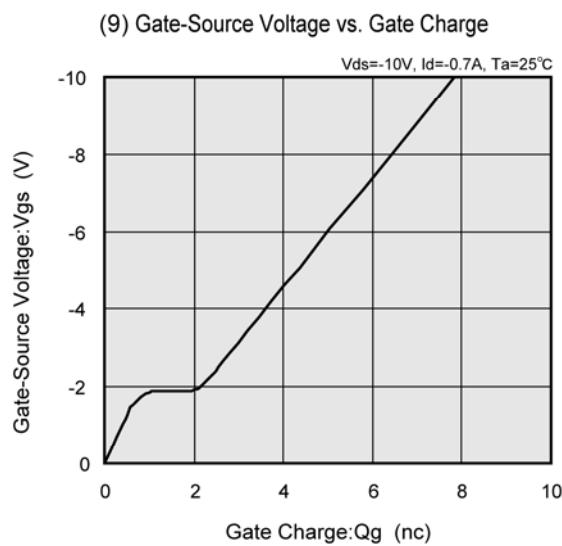
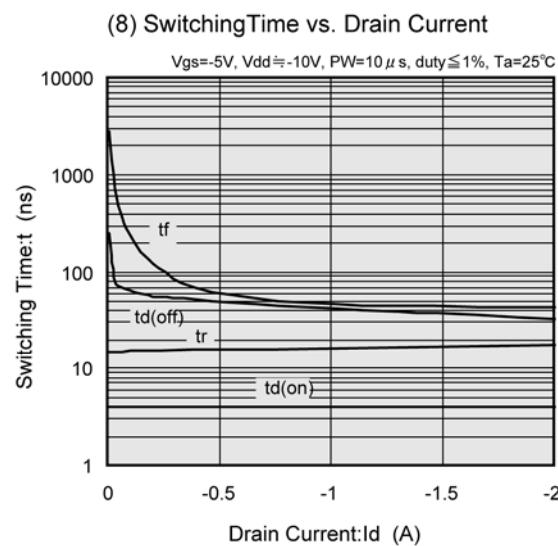
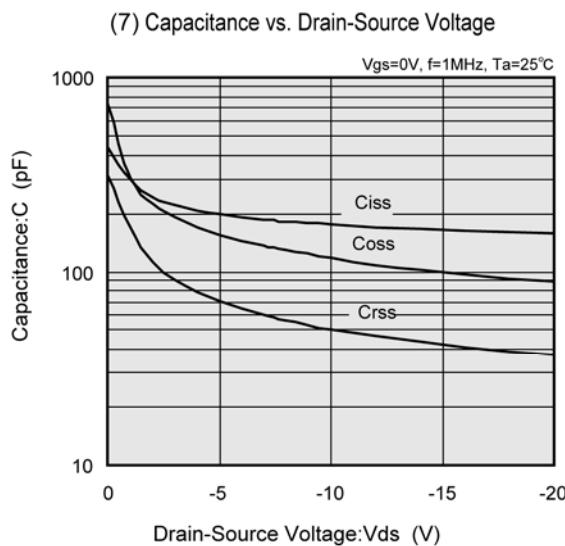
(5) Drain-Source On-State Resistance vs. Ambient Temperature



(6) Gate Source Cut-Off Voltage Variance vs. Ambient Temperature



## ■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



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